NCE N-Channel Super Trench Power MOSFET

Description

The NCEP1520K uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

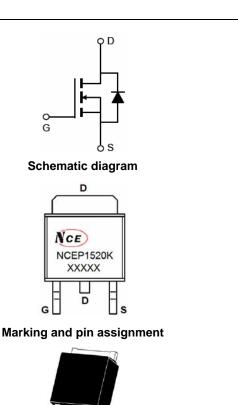
General Features

- V_{DS} =150V, I_D =20A $R_{DS(ON)}$ =59m Ω (typical) @ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- LED backlighting
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!



TO-252 -2Ltop view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP1520K	NCEP1520K	TO-252-2L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	150	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	20	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	14	Α
Pulsed Drain Current	I _{DM}	80	Α
Maximum Power Dissipation	P _D	68	W
Derating factor		0.45	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	65	mJ
Drain Source voltage slope, V _{DS} ≤ 120 V,	dv/dt	50	V/ns
Drain Source voltage slope, V _{DS} ≤ 120 V, I _{SD} <i<sub>D</i<sub>	dv/dt	50	V/ns
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	°C



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NCEP1520K

Thermal Characteristic

Thermal Résistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	2.2	°C/W
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Electrical Characteristics (T_A=25 [°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	150	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20 V , V_{DS} =0 V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.5	3.3	4.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =10A	-	59	65	mΩ
Gate resistance	R _G		-	4.5	-	Ω
Forward Transconductance	g FS	V _{DS} =5V,I _D =10A	15	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C _{lss}	\\ 75\\\\ 0\\	-	600		PF
Output Capacitance	C _{oss}	V_{DS} =75V, V_{GS} =0V, F=1.0MHz	-	74.7		PF
Reverse Transfer Capacitance	C _{rss}	r=1.0lvlm2	-	10.8		PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t _{d(on)}		-	9.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =75 V , R_L =7.5 Ω	-	5.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =3 Ω	-	12.5	-	nS
Turn-Off Fall Time	t _f		-	3	-	nS
Total Gate Charge	Qg	\/ -75\/ -104	-	12	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =75 V , I_{D} =10 A , V_{GS} =10 V	-	5.7	-	nC
Gate-Drain Charge	Q _{gd}	VGS-10V	-	2.7	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =10A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	20	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	29	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	130	-	nC

Notes:

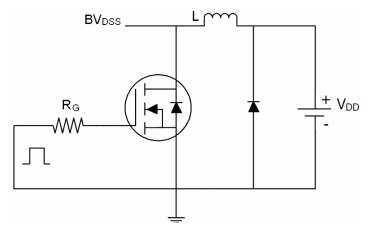
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω



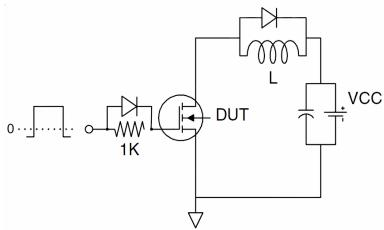
NCEP1520K

Test Circuit

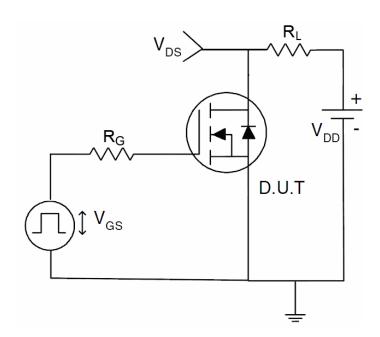
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





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Typical Electrical and Thermal Characteristics

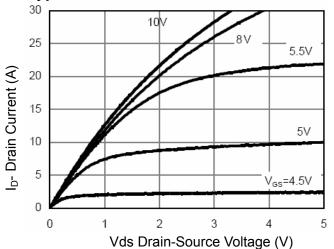


Figure 1 Output Characteristics

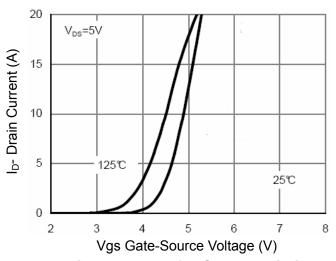


Figure 2 Transfer Characteristics

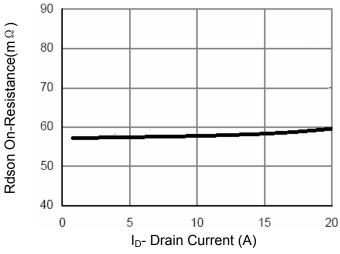


Figure 3 Rdson- Drain Current

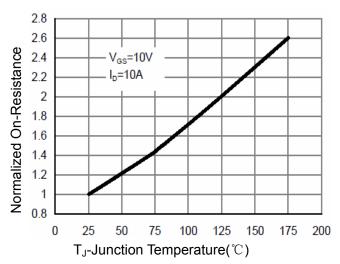


Figure 4 Rdson-Junction Temperature

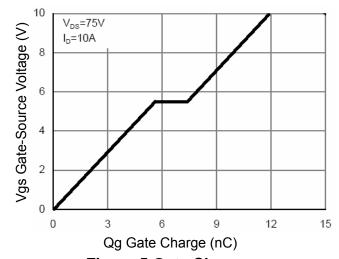


Figure 5 Gate Charge

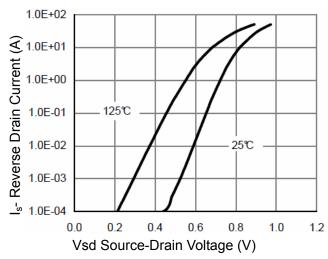


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)



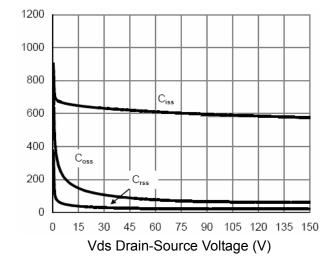


Figure 7 Capacitance vs Vds

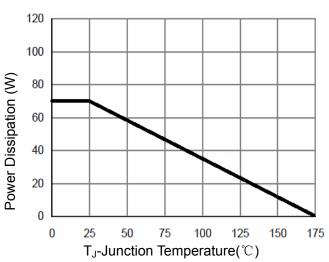


Figure 9 Power De-rating

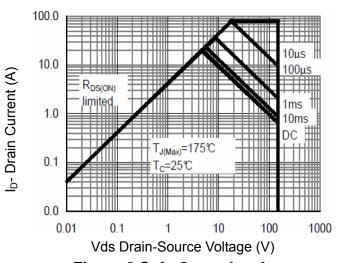


Figure 8 Safe Operation Area

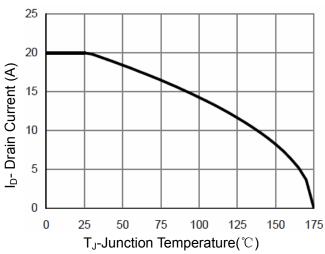
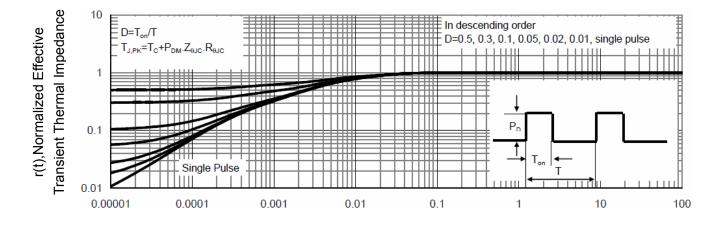


Figure 10 Current De-rating

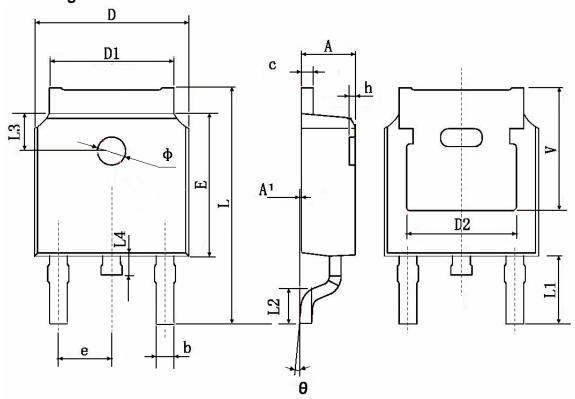


Square Wave Pluse Duration(sec) **Figure 11 Normalized Maximum Transient Thermal Impedance**



NCEP1520K

TO-252-2L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.83 TYP.		0.190 TYP.			
E	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.900	TYP.	0.114	TYP.		
L2	1.400	1.700	0.055	0.067		
L3	1.600	0 TYP. 0.063 TYP.		1.600 TYP.		TYP.
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350	TYP.	0.211 TYP.			



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